Serial No. 10/627,983 Docket No. T36-158111M/RS (NGB.274)

## **AMENDMENTS TO THE ABSTRACT:**

## Please replace the Abstract with the following amended Abstract:

A scintillator <u>includes</u> is made of a Group III nitride compound semiconductor layer that emits fluorescent light when radiated by, for example, a CU-Kα-ray source, an X-ray source, or a γ-ray source, and a scintillation counter including a scintillator having a Group III nitride compound semiconductor.

[marked corrected version]

[attach 2nd page - clean correct version]

## ABSTRACT OF THE DISCLOSURE

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A scintillator includes a Group III nitride compound semiconductor layer that emits fluorescent light when radiated by, for example, a CU-K $\alpha$ -ray source, an X-ray source, or a  $\gamma$ -ray source, and a scintillation counter including a scintillator having a Group III nitride compound semiconductor.